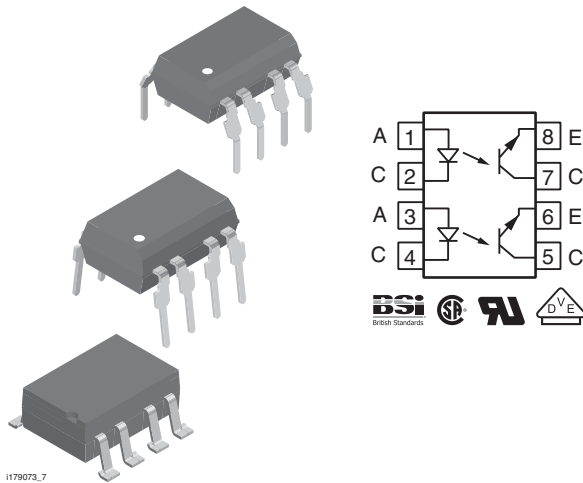


Optocoupler, Phototransistor Output, Dual Channel



1179073_7

DESCRIPTION

The ILD610 series is a dual channel optocoupler series for high density applications. Each channel consists of an optically coupled pair with a gallium arsenide infrared LED and silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD610 series is the dual version of SFH610 series and uses a repetitive pin-out configuration instead of the more common alternating pin-out used in most dual couplers.

FEATURES

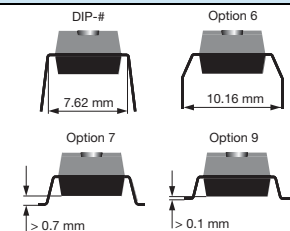
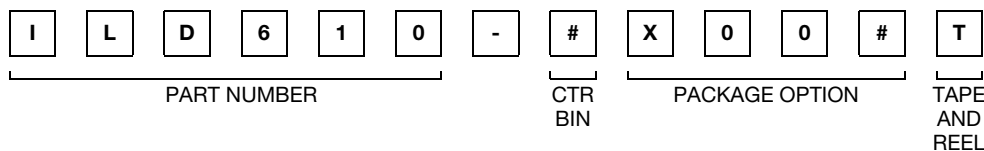
- Dual version of SFH610 series
- Isolation test voltage, 5300 V_{RMS}
- V_{CEsat} 0.25 (≤ 0.4) V at I_F = 10 mA, I_C = 2.5 mA
- V_{CEO} = 70 V
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884)/DIN EN 60747-5-5 pending
- CSA 93751
- BSI IEC 60950; IEC 60065

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
	40 to 80	63 to 125	100 to 200	160 to 320
UL, CSA, BSI				
DIP-8	ILD610-1	-	ILD610-3	-
DIP-8, 400 mil, option 6	-	-	ILD610-3X006	-
SMD-8, option 7	-	ILD610-2X007T	-	-
SMD-8, option 9	-	-	ILD610-3X009	ILD610-4X009

Note

- Additional options may be possible, please contact sales office.

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6.0	V
Surge forward current	$t \leq 1.0\text{ ms}$	I_{FSM}	1.5	A
Power dissipation		P_{diss}	100	mW
Derate linearly from $25\text{ }^{\circ}\text{C}$			1.3	mW/ $^{\circ}\text{C}$
Forward continuous current		I_F	60	mA
OUTPUT				
Collector emitter voltage		V_{CE}	70	V
Collector current		I_C	50	mA
	$t \leq 1.0\text{ ms}$	I_C	100	mA
Power dissipation		P_{diss}	150	mW
Derate linearly from $25\text{ }^{\circ}\text{C}$			2.0	mW/ $^{\circ}\text{C}$
COUPLER				
Isolation test voltage	$t = 1.0\text{ s}$	V_{ISO}	5300	V_{RMS}
Isolation resistance	$V_{IO} = 500\text{ V}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Storage temperature		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$
Operating temperature		T_{amb}	- 55 to + 100	$^{\circ}\text{C}$
Junction temperature		T_j	100	$^{\circ}\text{C}$
Lead soldering time at $260\text{ }^{\circ}\text{C}$			10	s

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 60 mA		V _F		1.25	1.65	V
Reverse current	V _R = 6.0 V		I _R		0.01	10	μA
Capacitance	V _R = 0 V, f = 1.0 MHz		C _O		25		pF
OUTPUT							
Collector emitter breakdown voltage	I _C = 10 mA, I _E = 10 μA		BV _{CEO}	70	90		V
			BV _{CEO}	6.0	7.0		V
Collector emitter dark current	V _{CE} = 10 V		I _{CEO}		2.0	50	nA
Collector emitter capacitance	V _{CE} = 5.0 V, f = 1.0 MHz		C _{CE}		7.0		pF
Collector emitter leakage current	V _{CE} = 10 V	ILD610-1	I _{CEO}		2.0	50	nA
		ILD610-2	I _{CEO}		2.0	50	nA
		ILD610-3	I _{CEO}		5.0	100	nA
		ILD610-4	I _{CEO}		5.0	100	nA
COUPLER							
Collector emitter saturation voltage	I _F = 10 mA, I _C = 2.5 mA		V _{CEsat}		0.25	0.40	V
Coupling capacitance			C _C		0.35		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

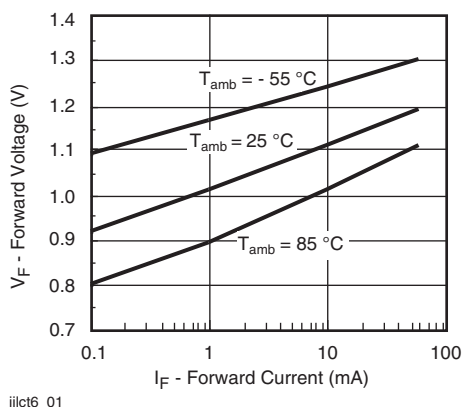


Optocoupler, Phototransistor Output, Dual Channel Vishay Semiconductors

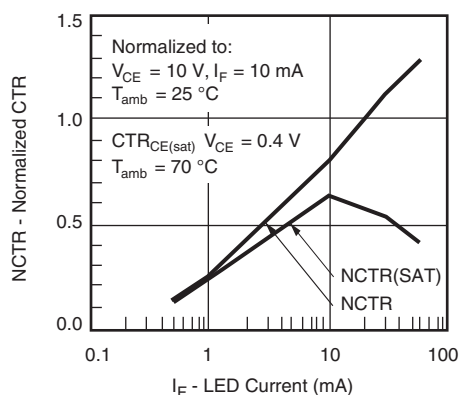
CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
CTR ⁽¹⁾	$I_F = 10\text{ mA}$, $V_{CE} = 5.0\text{ V}$	ILD610-1	CTR	40		80	%
		ILD610-2	CTR	63		125	%
		ILD610-3	CTR	100		200	%
		ILD610-4	CTR	160		320	%
	$I_F = 1.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$	ILD610-1	CTR	13			%
		ILD610-2	CTR	22			%
		ILD610-3	CTR	34			%
		ILD610-4	CTR	56			%

Note⁽¹⁾ CTR will match within a ratio of 1.7:1

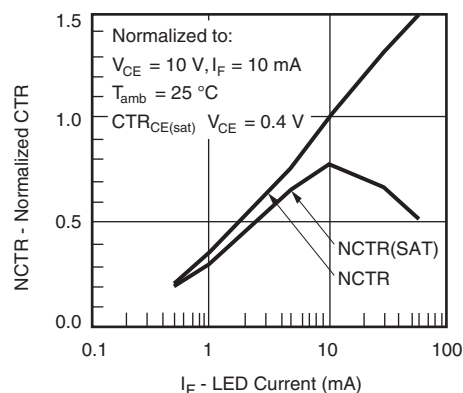
SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Rise time	V _{CC} = 5.0 V, R _L = 75 Ω, I _F = 10 mA	ILD610-1	t _r		2.0		μs
		ILD610-2			2.5		
		ILD610-3			2.9		
		ILD610-4			3.3		
Fall time	V _{CC} = 5.0 V, R _L = 75 Ω, I _F = 10 mA	ILD610-1	t _f		2.0		μs
		ILD610-2			2.6		
		ILD610-3			3.1		
		ILD610-4			3.5		
Turn-on time	V _{CC} = 5.0 V, R _L = 75 Ω, I _F = 10 mA	ILD610-1	t _{on}		3.0		μs
		ILD610-2			3.2		
		ILD610-3			3.6		
		ILD610-4			4.1		
Turn-off time	V _{CC} = 5.0 V, R _L = 75 Ω, I _F = 10 mA	ILD610-1	t _{off}		2.9		μs
		ILD610-2			3.4		
		ILD610-3			3.7		
		ILD610-4			4.1		
SATURATED							
Rise time	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 20 mA	ILD610-1	t _r		2.0		μs
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-2			2.8		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-3			2.8		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 5 mA	ILD610-4			4.6		
Fall time	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 20 mA	ILD610-1	t _f		11		μs
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-2			14		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-3			14		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 5 mA	ILD610-4			15		
Turn-on time	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 20 mA	ILD610-1	t _{on}		3.0		μs
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-2			4.3		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-3			4.3		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 5 mA	ILD610-4			6.0		
Turn-off time	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 20 mA	ILD610-1	t _{off}		18		μs
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-2			25		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 10 mA	ILD610-3			25		
	V _{CC} = 5.0 V, R _L = 1.0 kΩ, I _F = 5 mA	ILD610-4			25		

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

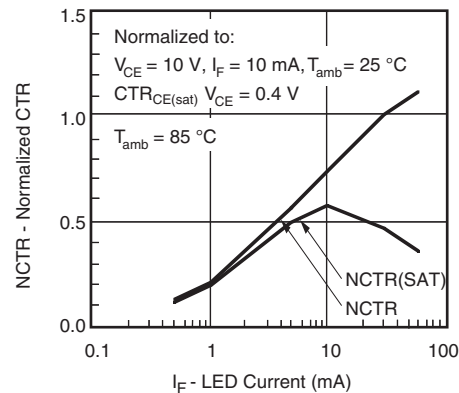
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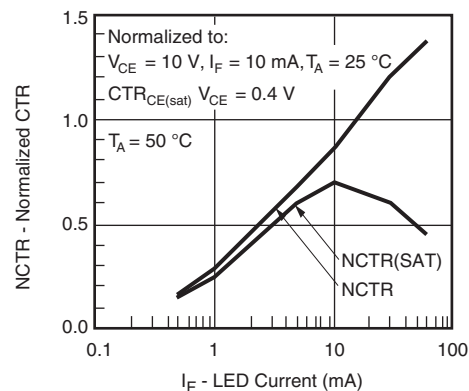
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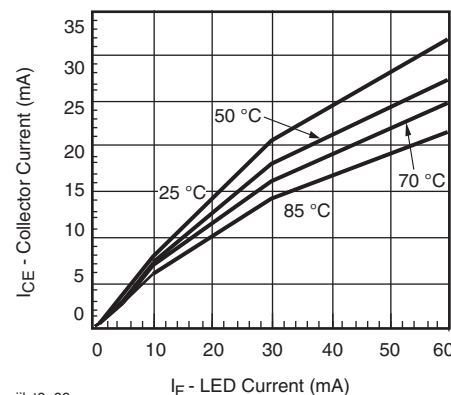
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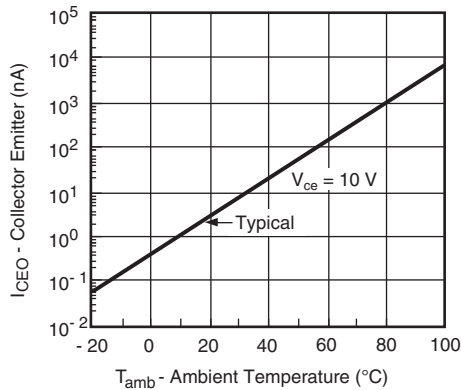
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iilct6_03

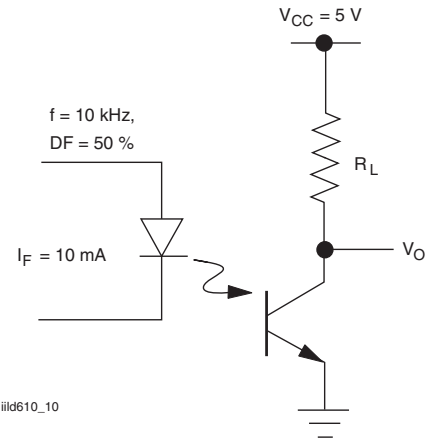


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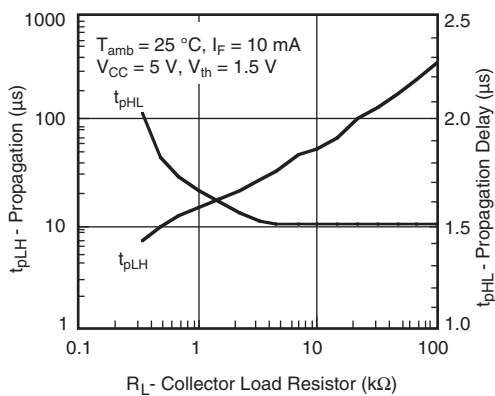
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Fig. 7 - Collector Emitter Leakage Current vs. Temperature



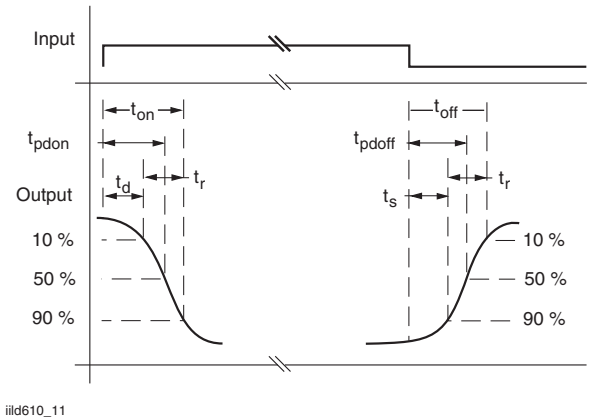
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Fig. 10 - Non-Saturated Switching Schematic



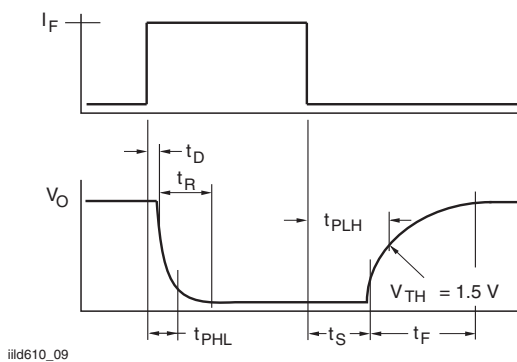
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Fig. 8 - Propagation Delay vs. Collector Load Resistor



iild610_11

Fig. 11 - Saturated Switching Time Test Waveform



iild610_09

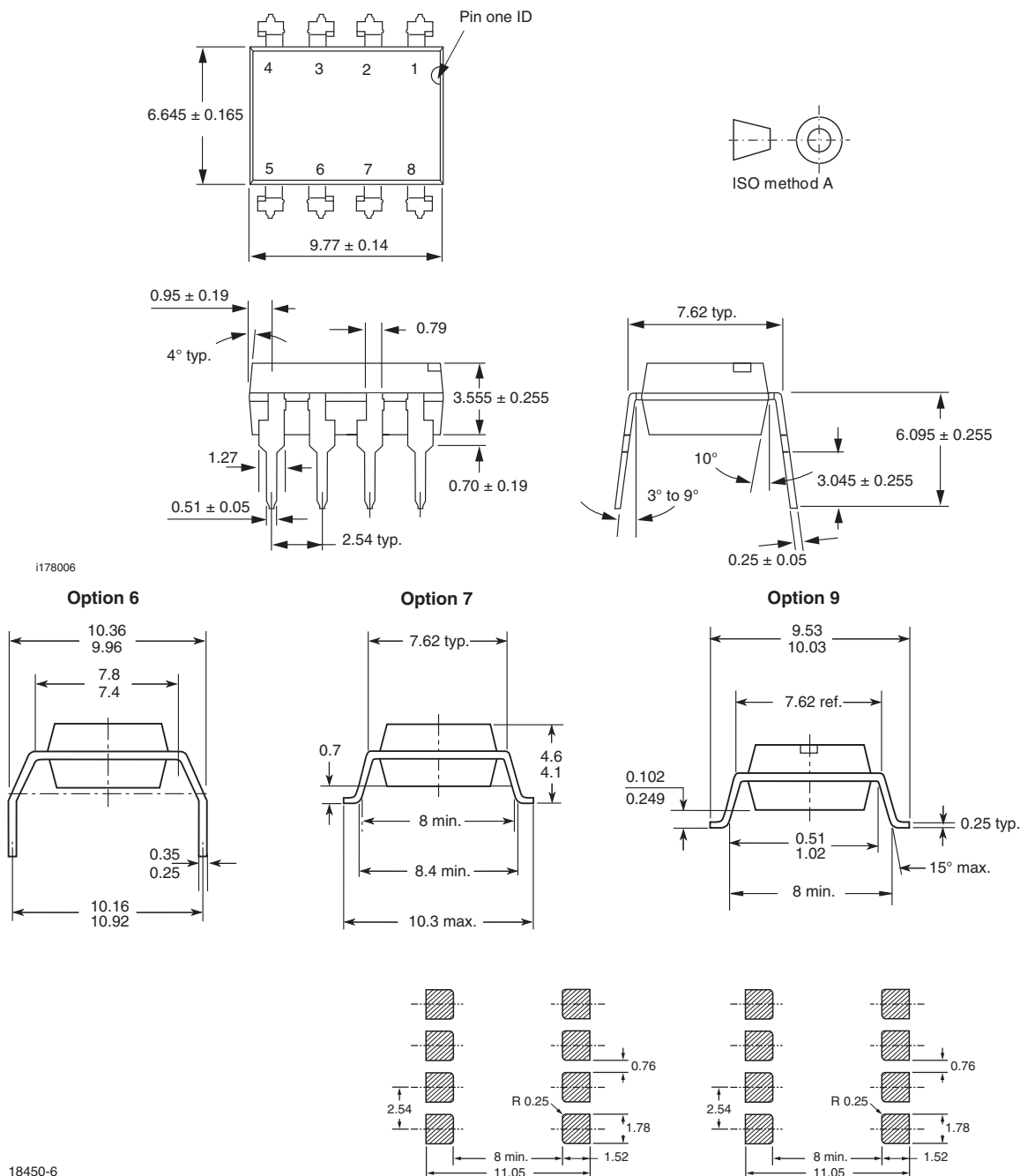
Fig. 9 - Switching Timing

ILD610

Vishay Semiconductors Optocoupler, Phototransistor Output, Dual Channel



PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING



Notes

- Only option 1 and 7 reflected in the package marking
- Tape and reel suffix (T) is not part of the package marking



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